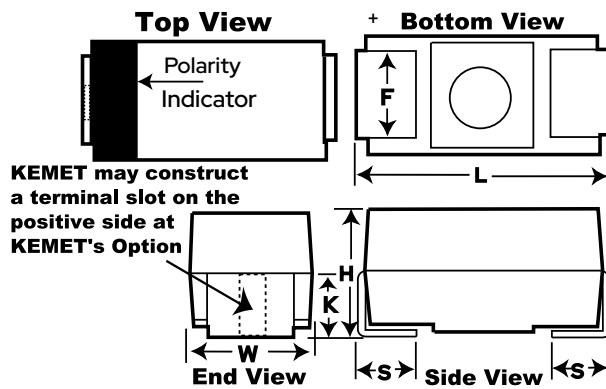


# T495X108K006ZTE100

Obsolete

B450, Tantalum, MnO2 Tantalum, Commercial Grade, 1,000 uF, 10%, 6.3 VDC, SMD, Molded, Low ESR, Surge Robust, 100 mOhms, 7343, 4.4 mm, 1.3 mm



General Information	
Series	B450
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, Molded, Low ESR, Surge Robust
Features	Low ESR, Surge Robust
RoHS	Yes
Termination	Tin
AEC-Q200	No

Specifications	
Capacitance	1,000 uF
Tolerance	10%
Voltage DC	6.3 VDC (85C), 4.22 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6%
Failure Rate	N/A
ESR	0.1 Ohms (100kHz)
Ripple Current	1280 mAmps (25C), 1152 mAmps (85C), 512 mAmps (125C)
Leakage Current	63 uA

Dimensions	
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
H	4.1mm +/-0.3mm
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	400

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